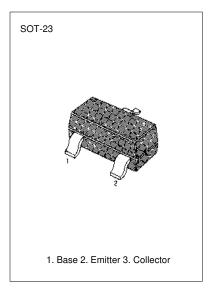
# PNP EPITAXIAL SILICON TRANSISTOR

## **SWITCHING AND AMPLIFIER APPLICATIONS**

- Suitable for automatic insertion in thick and thin-film circuits
- LOW NOISE: BC859, BC860
- Complement to BC846 ... BC850

# ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub>=25°C)

Characteristic	Symbol	Rating	Unit
Collector-Base Voltage : BC856 : BC857/860 : BC858/859 Collector-Emitter Voltage : BC856 : BC857/860 : BC857/860 : BC858/859 Emitter-Base Voltage Collector Current (DC) Collector Dissipation Junction Temperature Storage Temperature	V <sub>CBO</sub> V <sub>EBO</sub> I <sub>C</sub> P <sub>C</sub> T <sub>J</sub> T <sub>STG</sub>	-80 -50 -30 -65 -45 -30 -5 -100 310 150 -65 ~ 150	0,00 m W C C C C C C C C C C C C C C C C C C



# **ELECTRICAL CHARACTERISTICS (T<sub>A</sub>=25°C)**

Charac	eteristic	Symbol	Test Conditions	Тур	Max	Unit	
Collector Cut-off Current		I <sub>CBO</sub>	V <sub>CB</sub> = -30V, I <sub>E</sub> =0			-15	nA
DC Current Gain		h <sub>FE</sub>	$V_{CE}$ = -5V, $I_{C}$ = -2mA	110		800	
Collector-Emitter Saturation Voltage		V <sub>CE</sub> (sat)	$I_{C}=-10mA, I_{B}=-0.5mA$		-90	-300	mV
	· ·		$I_{C}$ = -100mA, $I_{B}$ = -5mA		-250	-650	mV
Collector-Base Saturation Voltage		V <sub>BE</sub> (sat)	$I_{C}= -10 \text{mA}, I_{B}= -0.5 \text{mA}$		-700		mV
			$I_{C}=-100\text{mA}, I_{B}=-5\text{mA}$		-900		mV
Base-Emitter On Voltage		V <sub>BE</sub> (on)	$V_{CE}$ = -5V, $I_{C}$ = -2mA	-600	-660	-750	mV
			$V_{CE} = -5V, I_{C} = -10mA$			-800	mV
Current Gain Bandwidth Product		f <sub>T</sub>	$V_{CE} = -5V, I_{C} = -10mA$		150		MHz
			f=100MHz				
Collector-Base Capacitance		C <sub>CBO</sub>	V <sub>CB</sub> = -10V, f=1MHz			6	pF
Noise Figure	: BC856/857/858	NF	$V_{CE} = -5V$ , $I_{C} = -200\mu A$		2	10	dB
· ·	: BC859/860		f=1KHz, $R_G$ =2K $\Omega$		1	4	dB
	: BC859	NF	$V_{CF} = -5V$ , $I_{C} = -200\mu A$			-	
		INF	R <sub>G</sub> =2KΩ		1.2	4	dB
	: BC860		f=30~15000Hz		1.2	2	dB

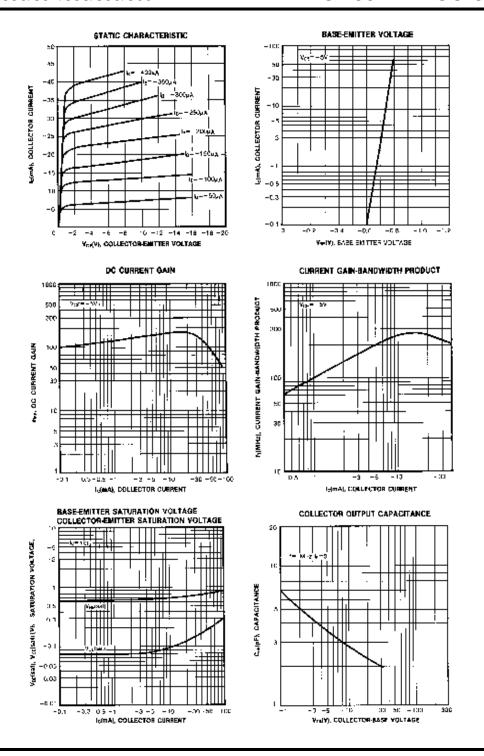
## **h**<sub>FE</sub> CLASSIFICATION

Classification	Α	В	С		
h <sub>FE</sub>	110-220	200-450	420-800		

# **MARKING CODE**

TYPE	856A	856B	856C	857A	857B	857C	858A	858B	858C	859A	859B	859C	860A	860B	860C
MARK	9AA	9AB	9AC	9BA	9BB	9BC	9CA	9CB	9CC	9DA	9DB	9DC	9EA	9EB	9EC







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E<sup>2</sup>CMOS<sup>™</sup> PowerTrench<sup>™</sup>

FACT<sup>TM</sup> QS<sup>TM</sup>

 $\begin{array}{lll} \mathsf{FACT} \ \mathsf{Quiet} \ \mathsf{Series^{\mathsf{TM}}} & \mathsf{Quiet} \ \mathsf{Series^{\mathsf{TM}}} \\ \mathsf{FAST}^{\circledast} & \mathsf{SuperSOT^{\mathsf{TM}}}\text{-3} \\ \mathsf{FASTr^{\mathsf{TM}}} & \mathsf{SuperSOT^{\mathsf{TM}}}\text{-6} \\ \mathsf{GTO^{\mathsf{TM}}} & \mathsf{SuperSOT^{\mathsf{TM}}}\text{-8} \\ \mathsf{HiSeC^{\mathsf{TM}}} & \mathsf{TinyLogic^{\mathsf{TM}}} \end{array}$ 

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